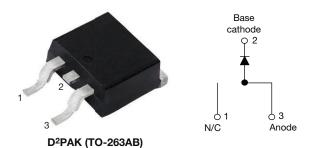




**Vishay Semiconductors** 

## High Performance Schottky Rectifier, 10 A



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub> 10 A					
V <sub>R</sub>	35 V, 45 V				
V <sub>F</sub> at I <sub>F</sub>	0.57 V				
I <sub>RM</sub>	15 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
E <sub>AS</sub>	8 mJ				
Package	D <sup>2</sup> PAK (TO-263AB)				
Circuit configuration	Single				

### FEATURES

- 150 °C T<sub>J</sub> operation
- TO-220 and D<sup>2</sup>PAK packages
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245  $^{\circ}\mathrm{C}$
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES UNITS								
I <sub>F(AV)</sub>	Rectangular waveform	10	٨					
I <sub>FRM</sub>	T <sub>C</sub> = 135 °C	20	A					
V <sub>RRM</sub>		35/45	V					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1060	А					
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.57	V					
TJ	Range	-65 to +150	C°					

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-MBRB1035-M3	VS-MBRB1045-M3	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	35	45	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>		40	v			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	VALUES	UNITS					
Maximum average forward current	I <sub>F(AV)</sub>	$T_{C}$ = 135 °C, rated $V_{R}$	T <sub>C</sub> = 135 °C, rated V <sub>R</sub>					
Peak repetitive forward current	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20 kł	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 135 °C					
Non-repetitive surge current	I <sub>FSM</sub>	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	1060	А			
		Surge applied at rated load conditions halfwave, single phase, 60 Hz		150				
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 2 \text{ A}, L = 4 \text{ mH}$		8	mJ			
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		2	А			



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## VS-MBRB1035-M3, VS-MBRB1045-M3

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ELECTRICAL SPECIFICATIONS							
PARAMETER	ETER SYMBOL TEST CONDITIONS						
		20 A	T <sub>J</sub> = 25 °C	0.84			
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	10 A	– T.I = 125 °C	0.57	V		
		20 A	$1_{\rm J} = 125  {}^{\circ}{\rm C}$	0.72			
Maximum instantaneous reverse	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	°C Detect DC welters				
current	IRM (')	T <sub>J</sub> = 125 °C	Rated DC voltage	15	mA		
Threshold voltage	V <sub>F(TO)</sub>			0.354	V		
Forward slope resistance	r <sub>t</sub>	$T_J = T_J maximum$		17.6	mΩ		
Maximum junction capacitance	CT	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal ra °C	$V_{R}$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 $^{\circ}\mathrm{C}$		pF		
Typical series inductance	L <sub>S</sub>	Measured from top of te	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs			

Note

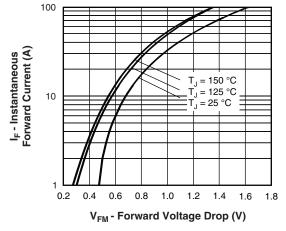
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

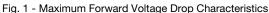
THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction tempera	ature range	TJ		-65 to 150	°C		
Maximum storage tempera	ture range	T <sub>Stg</sub>		-65 to 175	C		
Maximum thermal resistan junction to case	ce,	R <sub>thJC</sub>	DC operation	2.0	°C/W		
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth, and greased (Only for TO-220)	0.50	C/W		
Approximate weight				2	g		
Approximate weight				0.07	oz.		
Mounting torgue	minimum			6 (5)	kgf ⋅ cm		
maximum				12 (10)	(lbf · in)		
Marking daviaa			Case style D <sup>2</sup> PAK (TO-263AB)	MBRE	31035		
Marking device			Case Sigle D-FAR (10-203AB)	MBRE	31045		



## VS-MBRB1035-M3, VS-MBRB1045-M3

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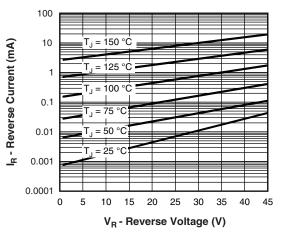


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

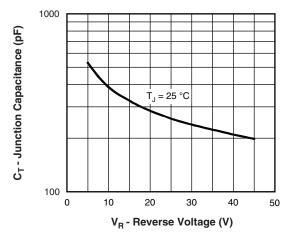
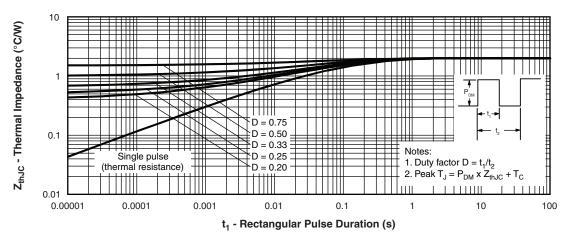


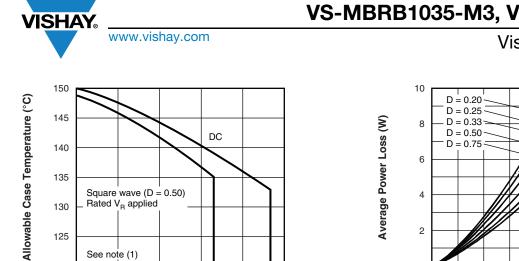
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





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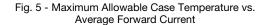
IF(AV) - Average Forward Current (A)

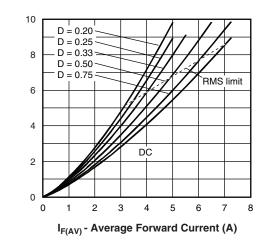
6

9

12

15







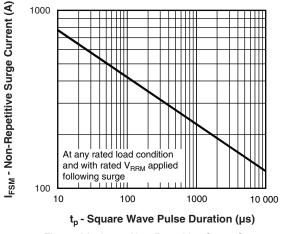


Fig. 7 - Maximum Non-Repetitive Surge Current

### Note

120

0

3

 $\begin{array}{l} \mbox{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \mbox{forward power loss} = I_{F(AV)} \times V_{FM} \mbox{ at } (I_{F(AV)}/D) \mbox{ (see fig. 6)}; \\ Pd_{REV} = \mbox{inverse power loss} = V_{R1} \times I_R \mbox{ (1 - D)}; \mbox{ } I_R \mbox{ at } V_{R1} = \mbox{rated } V_R \mbox{ } \mbox{ } \end{array}$ (1)

## VS-MBRB1035-M3, VS-MBRB1045-M3

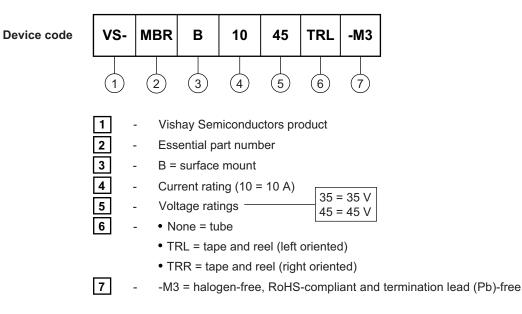
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## **Vishay Semiconductors**

### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-MBRB1035-M3	50	Antistatic plastic tubes					
VS-MBRB1035TRL-M3	800	13" diameter plastic tape and reel					
VS-MBRB1035TRR-M3	800	13" diameter plastic tape and reel					
VS-MBRB1045-M3	50	Antistatic plastic tubes					
VS-MBRB1045TRL-M3	800	13" diameter plastic tape and reel					
VS-MBRB1045TRR-M3	800	13" diameter plastic tape and reel					

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?96164						
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96424					
SPICE model	www.vishay.com/doc?95293					

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D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INCHES		NOTES	
	MIN.	MAX.	MIN.	MAX.	NOTES	
A	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STNDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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